REVISIONS			
LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Add device types 03 and 04. Technical and editorial changes throughout.	92-04-27	M. A. Frye

THE ORIGINAL FIRST PAGE OF THIS DRAWING HAS BEEN REPLACED

REV																			
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REV STATUS OF SHEETS	REV	A	A	A	A	A	A	A	A	A	A	A	A		
	SHEET	1	2	3	4	5	6	7	8	9	10	11	12		

PMIC N/A

STANDARDIZED MILITARY DRAWING

THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE

AMSC N/A

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DRAWING APPROVAL DATE
89-09-28

REVISION LEVEL
A

DEFENSE ELECTRONICS SUPPLY CENTER
DAYTON, OHIO 45444

MICROCIRCUITS, DIGITAL, FAST CMOS, UP/DOWN BINARY COUNTER WITH PRESET AND RIPPLE CLOCK, TTL COMPATIBLE, MONOLITHIC SILICON

SIZE	CAGE CODE	5962-89733
A	67268	

SHEET 1 OF 12

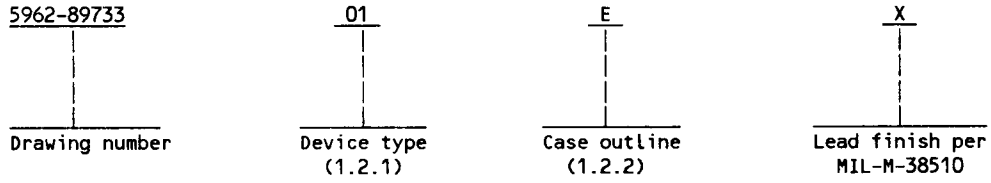
DESC FORM 193
JUL 91

5962-E304

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 Device type(s). The device type(s) shall identify the circuit function as follows:

Device type	Generic number	Circuit function
01 1/	54FCT191	UP/DOWN binary counter with preset and ripple clock, TTL compatible
02 1/	54FCT191A	UP/DOWN binary counter with preset and ripple clock, TTL compatible
03	54FCT191	UP/DOWN binary counter with preset and ripple clock, TTL compatible
04	54FCT191A	UP/DOWN binary counter with preset and ripple clock, TTL compatible

1.2.2 Case outline(s). The case outline(s) shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
E	D-2 (16-lead, .840" x .310" x .200"), dual-in-line package
F	F-5 (l6-lead, .440" x .285" x .085"), flat package
2	C-2 (20-terminal, .358" x .358" x .100"), square chip carrier package

1.3 Absolute maximum ratings. 2/

Supply voltage range (V_{CC})	-0.5 V dc to +7.0 V dc
Input voltage range	-0.5 V dc to V_{CC} + 0.5 V dc 3/
Output voltage range	-0.5 V dc to V_{CC} + 0.5 V dc 3/
DC input diode current (I_{IK})	-20 mA
DC output diode current (I_{OK})	-50 mA
DC output current	±100 mA
Power dissipation (P_D) 4/	500 mW
Thermal resistance (Θ_{JC})	See MIL-M-38510, appendix C
Storage temperature range	-65°C to +150°C
Junction temperature (T_J)	+175°C
Lead temperature (soldering, 10 seconds)	+300°C

1/ Due to internal noise problems, device types 01 and 02 do not meet the minimum V_{IH} threshold limit characteristic of the FCT family or the limits specified on this drawing. This device type is no longer available for acquisition.
2/ All voltage are referenced to GND.
3/ For V_{CC} > 6.5 V dc, the upper bound is limited to V_{CC}.
4/ Must withstand the added P_D due to short circuit test e.g., I_{OS}.

1.4 Recommended operating conditions.

Supply voltage range (V_{CC})	+4.5 V dc to +5.5 V dc
Maximum logic low voltage (V_{IL})	0.8 V dc
Minimum logic high voltage (V_{IH}) 5/	2.0 V dc
Case operating temperature range (T_C)	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 Government specification, standard, and bulletin. Unless otherwise specified, the following specification, standard, and bulletin of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510 - Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

(Copies of the specification, standard, and bulletin required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.2 herein.

3.2.2 Terminal connection(s). The terminal connection(s) shall be as specified on figure 1 herein.

3.2.3 Truth table and mode select table. The truth table and mode select table shall be as specified on figure 2 herein.

3.2.4 Logic diagram. The logic diagram shall be as specified on figure 3 herein.

3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full case operating temperature range.

5/ For dynamic operation of device types 01 and 02, a V_{IH} level between 2.0 V and 3.0 V may be recognized by this device as a high logic level input. For static operation of device type 01, a $V_{IH} \geq 2.0$ V will be recognized by these devices as a high logic level input. Users are cautioned to verify that this change will not affect their system.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions $-55°C \le T_C \le +125°C$ V_{CC} = 5.0 V dc ±10%	Device type	Group A subgroups	Limits		Unit
					Min	Max	
High level output voltage	V_{OH} 1/	V_{CC} = 4.5 V, V_{IL} = 0.8 V, V_{IH} = 2.0 V; I_{OH} = -300 µA	All	1, 2, 3	4.3		V
		I_{OH} = -12 mA	All	1, 2, 3	2.4		
Low level output voltage	V_{OL} 1/	V_{CC} = 4.5 V, V_{IL} = 0.8 V, V_{IH} = 2.0 V; I_{OL} = 300 µA 2/	All	1, 2, 3		0.2	V
		I_{OH} = 32 mA	All	1, 2, 3		0.5	
Input clamp voltage	V_{IK}	V_{CC} = 4.5 V, I_N = -18 mA	All	1, 2, 3		-1.2	V
High level input current	I_{IH}	V_{CC} = 5.5 V, V_{IN} = 5.5 V	All	1, 2, 3		5.0	µA
Low level input current	I_{IL}	V_{CC} = 5.5 V, V_{IN} = GND	All	1, 2, 3		-5.0	
Short circuit output current	I_{OS}	V_{CC} = 5.5 V 3/, V_{OUT} = GND	All	1, 2, 3	-60		mA
Quiesecent power supply current (CMOS inputs)	I_{CCQ}	V_{CC} = 5.5 V, $V_{IN} \le$ 0.2 V or $V_{IN} \ge$ 5.3 V, $f_I = f_{CP}$ = 0 MHz	All	1, 2, 3		1.5	mA
Quiesecent power supply current (TTL inputs)	ΔI_{CC}	V_{CC} = 5.5 V, V_{IN} = 3.4 V 4/	All	1, 2, 3		2.0	
Dynamic power supply current	I_{CCD}	V_{CC} = 5.5 V, $V_{IN} \ge$ 5.3 V or $V_{IN} \le$ 0.2 V, outputs open, one bit toggling, 50 percent duty cycle, PL = CE = U/D = CP = GND, 5/ Preset mode	All			0.25	mA/MHz
Total power supply current 6/	I_{CC}	V_{CC} = 5.5 V, outputs open, $V_{IN} \ge$ 5.3 V or $V_{IN} \le$ 0.2 V, f_I = 5 MHz, one bit toggling, 50 percent duty cycle, Preset mode, PL = CE = U/D = CP = GND	All	1, 2, 3		2.75	mA
		V_{CC} = 5.5 V, outputs open, V_{IN} = 3.4 V or V_{IN} = GND, f_I = 5 MHz, one bit toggling, 50 percent duty cycle, Preset mode, PL = CE = U/D = CP = GND	All	1, 2, 3		3.75	

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55°C \le T_C \le +125°C$ V_{CC} = 5.0 V dc ±10%	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Functional tests	7/	See 4.3.1d	All	7, 8			
Input capacitance	C_{IN}	See 4.3.1c	All	4		10	pF
Output capacitance	C_{OUT}	See 4.3.1c	All	4		12	pF
Propagation delay time, CP to Qn	t_{PLH1} t_{PHL1}	C_L = 50 pF minimum R_L = 500Ω 8/ See figure 4	01, 03	9, 10, 11	1.5	16.0	ns
			02, 04		1.5	10.5	
Propagation delay time, CP to TC	t_{PLH2} t_{PHL2}		01, 03	9, 10, 11	2.0	16.0	ns
			02, 04		2.0	10.5	
Propagation delay time, CP to RC	t_{PLH3} t_{PHL3}		01, 03	9, 10, 11	1.5	12.5	ns
			02, 04		1.5	8.2	
Propagation delay time, CE to RC	t_{PLH4} t_{PHL4}		01, 03	9, 10, 11	2.0	8.5	ns
			02, 04		2.0	5.6	
Propagation delay time, U/D to RC	t_{PLH5} t_{PHL5}		01, 03	9, 10, 11	4.0	22.5	ns
			02, 04		4.0	14.7	
Propagation delay time, U/D to TC	t_{PLH6} t_{PHL6}		01, 03	9, 10, 11	3.0	13.0	ns
			02, 04		3.0	8.5	
Propagation delay time, Pn to Qn	t_{PLH7} t_{PHL7}		01, 03	9, 10, 11	1.5	16.0	ns
			02, 04		1.5	10.4	
Propagation delay time, PL to Qn	t_{PLH8} t_{PHL8}		01, 03	9, 10, 11	3.0	14.0	ns
			02, 04		3.0	9.1	
Minimum setup time, Pn to PL	t_{s1}		01, 03	9, 10, 11	6.0		ns
			02, 04		5.0		
Minimum setup time, CE to CP	t_{s2}		01, 03	9, 10, 11	10.5		ns
			02, 04		9.5		

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55°C \le T_C \le +125°C$ V_{CC} = 5.0 V dc ±10%	Device type	Group A subgroups	Limits		Unit
					Min	Max	
Minimum setup time, U/D to CP	t_{s3}	C_L = 50 pF minimum, R_L = 500 Ω, See figure 4	01, 03	9, 10, 11	12.0		ns
			02, 04		10.0		
Minimum hold time, Pn to PL	t_{h1}		01, 03	9, 10, 11	1.5		ns
			02, 04		1.5		
Mihold setup time, CE to CP	t_{h2}		01, 03	9, 10, 11	0.0		ns
			02, 04		0.0		
Minimum hold time, U/D to CP	t_{h3}		01, 03	9, 10, 11	0.0		ns
			02, 04		0.0		
Minimum pulse width, PL	t_{w1}		01, 03	9, 10, 11	8.5		ns
			02, 04		8.0		
Minimum pulse width, CP	t_{w2}		01, 03	9, 10, 11	7.0		ns
			02, 04		6.0		
Minimum recovery time, PL to CP	t_{rec}		01, 03	9, 10, 11	7.5		ns
			02, 04		6.5		

1/ For dynamic operation of device types 01 and 02, a V_{IH} level between 2.0 V and 3.0 V may be recognized by this device as a high logic level input. For static operation of device type 01 and 02, a $V_{IH} \ge 2.0$ V will be recognized by this device as a high logic level input. Users are cautioned to verify that this change will not affect their system.

2/ Guaranteed by testing at worst case condition of V_{CC} = 3 volts.

3/ Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed 1 second.

4/ In accordance with TTL driven input (V_{IN} = 3.4 V dc); all other outputs at V_{CC} or GND.

5/ This parameter is not directly testable, but is derived for use in total power supply calculations.

6/ $I_{CC} = I_{CCQ} + (\Delta I_{CC} \times D_H \times N_T) + I_{CCD} (fcp/2 + f_I \times N_I)$.
Where D_H = Duty cycle for TTL inputs high.
N_T = Number of TTL inputs at D_H.
f_I = Input frequency in MHz.
N_I = Number of inputs at f_I.

7/ Due to internal noise problems, device types 01 and 02 cannot meet the threshold limits required in accordance with MIL-STD-883, test method 5004, for the V_{IH} minimum limit (2.0 V) of this technology family. For device types 03 and 04, use a V_{IH} limit of 3.0 V. The V_{IL} limit (0.8 V) remains unchanged. Users are cautioned to verify that this change will not affect their system.

8/ Minimum limits are guaranteed, if not tested on propagation delays.

Device types	01, 02, 03, and 04	
Case outlines	E, F	2
Terminal number	Terminal symbol	
1	P1	NC
2	Q1	P1
3	$\overline{Q0}$	Q1
4	$\overline{CE}$	$\overline{Q0}$
5	U/D	CE
6	Q2	$\overline{NC}$
7	Q3	U/D
8	GND	Q2
9	P3	Q3
10	$\overline{P2}$	GND
11	PL	NC
12	$\overline{TC}$	P3
13	RC	$\overline{P2}$
14	CP	PL
15	PO	TC
16	V_{CC}	$\overline{NC}$
17	---	RC
18	---	CP
19	---	PO
20	---	V_{CC}

FIGURE 1. Terminal connections.

$\overline{RC}$ truth table

Inputs			Outputs
$\overline{CE}$	TC	CP	$\overline{RC}$
L	H	⌐_⌐	⌐_⌐
H	X	X	H
X	L	X	H

Mode select table

Inputs				Mode
$\overline{PL}$	$\overline{CE}$	$\overline{U/D}$	CP	
H	L	L	↑	Count up
H	L	H	↑	Count down
L	X	X	X	Preset (Asynch)
H	H	X	X	No change

H = High voltage level
L = Low voltage level
X = Irrelevant
↑ = One low level pulse
⌐_⌐ = Transition from low to high

FIGURE 2. Truth table and mode select table.

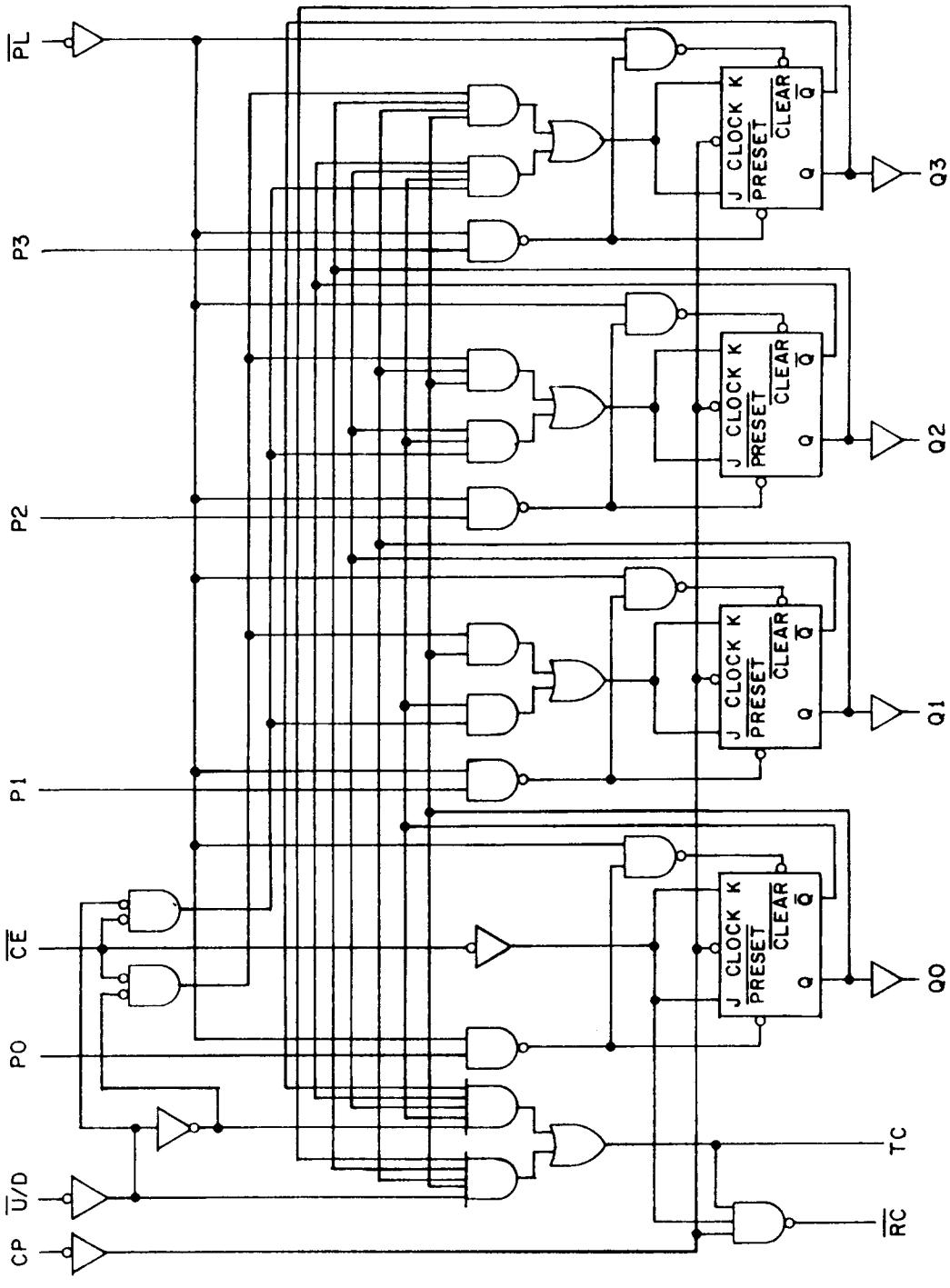
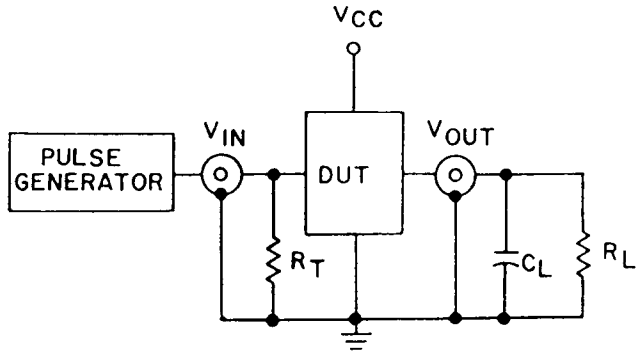
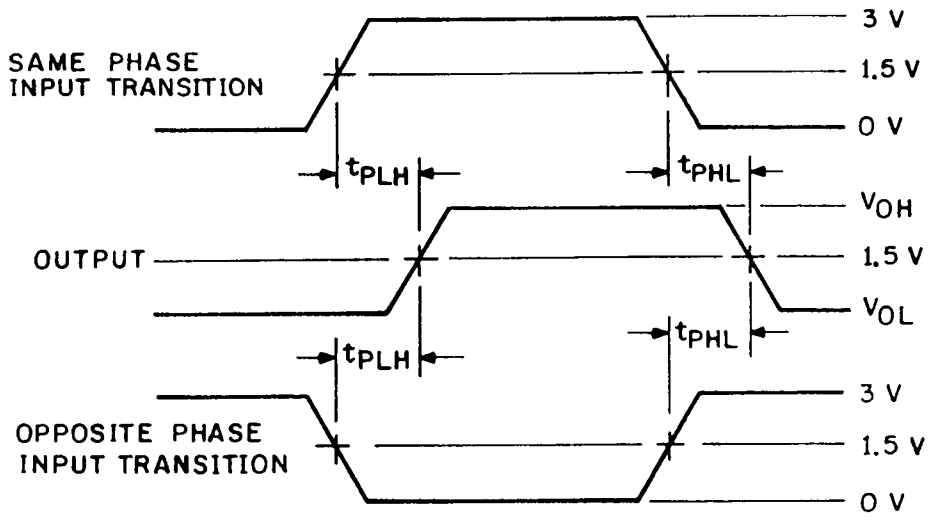


FIGURE 3. Logic diagram.





Definitions:
R_L = Load resistor, (see ac characteristics for value).
C_L = Load capacitance = 50 pF minimum, includes jig and probe capacitance.
R_T = Termination should be equal to Z_{OUT} of pulse generator.

FIGURE 4. Test circuit and switching waveforms.

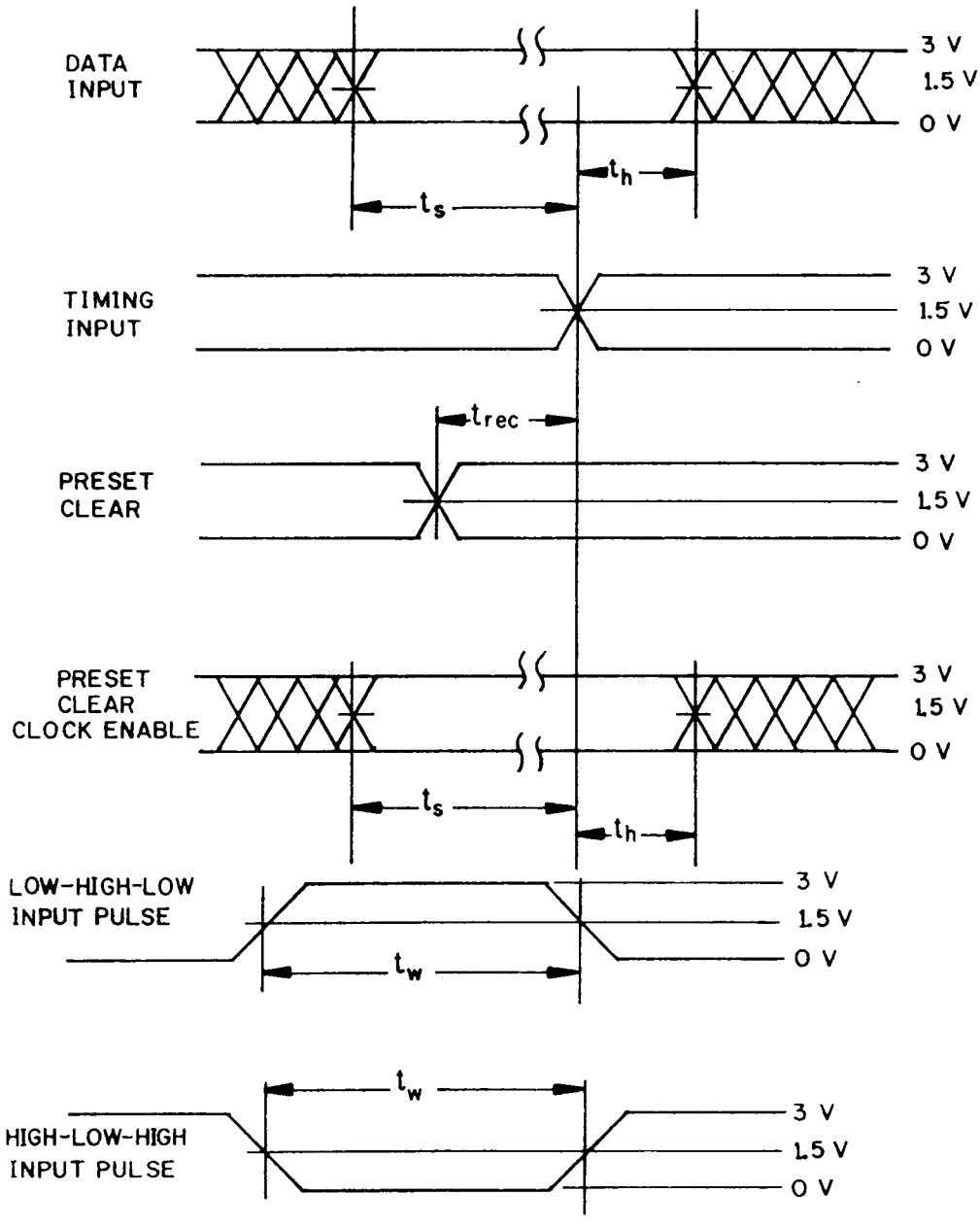


FIGURE 4. Test circuit and switching waveforms - Continued.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.

3.5 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103 (see 6.6 herein).

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.9 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).

(2) T_A = +125°C, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4, 7, 8, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

* PDA applies to subgroup 1.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

4.3.1 Group A inspection.

a. Tests shall be as specified in table II herein.

b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

c. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only initial test and after process or design changes which may affect capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Test all applicable pins on 5 devices with zero failures.

d. Subgroups 7 and 8 tests shall verify the truth table as specified on figure 2.

4.3.2 Groups C and D inspections.

a. End-point electrical parameters shall be as specified in table II herein.

b. Steady-state life test conditions, method 1005 of MIL-STD-883.

(1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.6 herein).

(2) T_A = +125°C, minimum.

(3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.4 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-ECS, telephone (513) 296-6022.

6.5 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-BUL-103. Additional sources will be added to MIL-BUL-103 as they become available. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-ECS. The approved sources of supply listed below are for information purposes only and are current only to the date of the last action of this document.